### **Peak EMI Reducing Solution**

#### **Features**

- Generates an EMI optimized clocking signal at output.
- Input frequency 14.31818 MHz.
- Frequency outputs:
  - o 120 MHz (modulated) default.
  - 72 MHz (modulated) or 48 MHz (modulated) selectable via I2C
- ± 1% Centre spread.
- Modulation rate: 40 KHz.
- Byte Write via I2C
- Supply voltage range 3.3V ± 0.3V.
- Available in 8-pin SOIC Package.
- Available in Commercial and Industrial Temperature ranges.

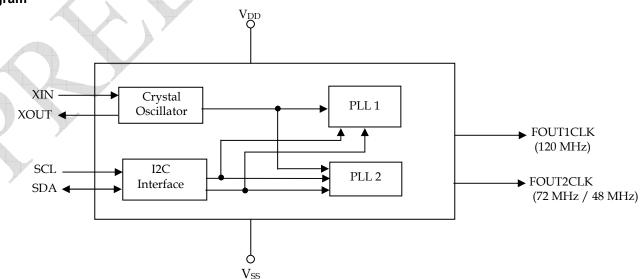
#### **Product Description**

The ASM3P2508A is a versatile spread spectrum frequency modulator. The ASM3P2508A reduces electromagnetic interference (EMI) at the clock source.

The ASM3P2508A allows significant system cost savings by reducing the number of circuit board layers and shielding that are required to pass EMI regulations. The ASM3P2508A modulates the output of PLL in order to spread the bandwidth of a synthesized clock, thereby decreasing the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most clock generators. Lowering EMI by increasing a signal's bandwidth is called spread spectrum clock generation.

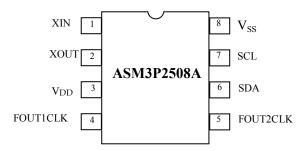
The ASM3P2508A has a feature to power down the 72MHz/48MHz output by writing data into specific registers in the device via I2C. By writing a '0' into bit 1 of Byte 0, the PLL block generating 72 MHz / 48MHz can be powered down. Writing '0' into bit '7' of Byte 1 selects an output of 72 MHz on FOUT2CLK while a '1' at the same location selects a 48 MHz clock output. However, the I2C block, crystal oscillator, and the PLL block generating 120MHz would be always running.

### **Block Diagram**





# **Pin Configuration**



# **Pin Description**

Pin Name	Type	Description
XIN	1	Connection to crystal
XOUT	0	Connection to crystal
$V_{DD}$	Р	Power supply for the analog and digital blocks
FOUT1CLK	0	Clock output-1 (120 MHz) - default
FOUT2CLK	0	Clock output-2 ( 72 MHz / 48 MHz)
SDA	I/O	I2C Data
SCL	Į.	I2C Clock
$V_{SS}$	Р	Ground to entire chip



# **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit
$V_{DD}, V_{IN}$	Voltage on any pin with respect to Ground	-0.5 to +7.0	V
T <sub>STG</sub>	Storage temperature	-65 to +125	°C
T <sub>A</sub>	Operating temperature	0 to 70	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
$T_DV$	Static Discharge Voltage	2	KV
	(As per JEDEC STD 22- A114-B)		
Note: These are device rel	stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings iability.	s for prolonged periods of time	may affect

# **Operating Conditions**

Parameter	Symbol	Condition / Description	Min	Тур	Max	Unit
Supply Voltage	$V_{DD}$	3.3V ± 10%	3	3.3	3.6	V
Ambient Operating Temperature Range	T <sub>A</sub>		-10		+70	°C
Crystal Resonator Frequency	F <sub>XIN</sub>			14.3	1818	MHz
Serial Data Transfer Rate		Standard Mode	10		100	Kb/s
Output Driver Load Capacitance	CL	A			15	pF



**DC Electrical Characteristics** (Test Condition : All the parameters are measured at room temperature (25°C) , unless otherwise stated)

Parameter	Symbol	Conditions / Description	Min	Тур	Max	Unit
Overall						
Supply Current, Dynamic	I <sub>cc</sub>	V <sub>DD</sub> =3.3V, F <sub>CLK</sub> =14.31818MHz, C <sub>L</sub> =15pF	40	49	60	mA
Supply Current, Static	I <sub>DD</sub>	V <sub>DD</sub> = 3.3V, Software Power Down*	27	35	43	mA
All input pins						
High-Level Input Voltage	V <sub>IH</sub>	V <sub>DD</sub> =3.3V	2.0	-	V <sub>DD</sub> +0.3	V
Low-Level Input Voltage	V <sub>IL</sub>	V <sub>DD</sub> =3.3V	V <sub>SS</sub> -0.3		0.8	V
High-Level Input Current	I <sub>IH</sub>		-1	-	1	$\mu$ A
Low-Level Input Current (pull-up)	I <sub>IL</sub>	4	-20	-36	-80	μΑ
Clock Outputs (FOU	T1CLK, FOUT2	CLK)				
High-Level Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> = 3.3V, I <sub>OH</sub> = 20mA	2.5	-	3.3	V
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>DD</sub> = 3.3V, I <sub>OL</sub> = 20mA	0	-	0.4	V
Output Impodance	Z <sub>OH</sub>	V <sub>O</sub> =0.5V <sub>DD</sub> ; output driving high	-	29		Ω
Output Impedance	Z <sub>OL</sub>	Vo=0.5V <sub>DD</sub> ; output driving low	-	27	-	52
* FOUT1CLK (120MHz) is fu	inctional and not loa	ded				



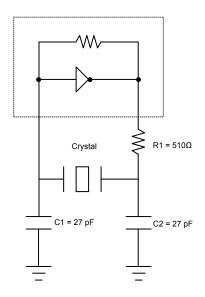
rev 1.3

# **AC Electrical Characteristics**

Parameter	Symbol	Conditions/ Description			Тур	Max	Unit
Rise Time	tr	$V_0 = 0.8V$ to 2.0V; $C_L = 15pF$	FOUT1CLK	640	680	750	pS
Nise Time	ιŗ	V <sub>0</sub> = 0.8V to 2.0V, C <sub>L</sub> = 13βF	FOUT2CLK	440	480	600	ρο
Fall Time	t <sub>f</sub>	$V_{\rm O}$ = 2.0V to 0.8V; $C_{\rm L}$ = 15pF	FOUT1CLK	660	720	800	pS
raii Tiitie	L†	V <sub>0</sub> = 2.0 V to 0.8 V, C <sub>L</sub> = 13βF	FOUT2CLK	460	520	570	ρο
Clock Duty Cycle	t <sub>D</sub>	Ratio of pulse width (as measure to next falling edge at 2.5V) to o		45	_	55	%
Frequency	£	Output Frequency =120MHz		-	±2.73	-	0/
Deviation	$f_D$	Output Frequency =72MHz /48	B MHz	A	- ±1.78 -	%	
Jitter, Long		On rising edges 500 uS apart at 2.5 V relative to an ideal clock, PLL B inactive *			45		pS
Term	Tj <sub>(LT)</sub>	On rising edges 500 uS apart at 2.5 V relative ideal clock, PLL B active *		1	165	-	ρ
Jitter, peak to	Ti	From rising edge to next rising PLL B inactive *	edge at 2.5 V,	-	110	-	pS
peak	Tj <sub>(ΔT)</sub>	From rising edge to next rising PLL B active *		390	ı	ρ	
Clock Stabilization Time	t <sub>STB</sub>	Output active from power up, R Software Power Down	-	125	-	μS	
* CL = 15 pF, Fxin =	= 14.31818 MHz						



# **Typical Crystal Oscillator Circuit**



# **Typical Crystal Specifications**

Fundamental AT cut parallel resonant crystal				
Nominal Frequency	14.31818 MHz			
Frequency Tolerance	+/- 50 ppm or better at 25°C			
Operating temperature range	-20°C to +85°C			
Storage Temperature	-40°C to +85°C			
Load Capacitance	18pF			
Shunt capacitance	7 pF maximum			
ESR	25 Ω			



#### **I2C Serial Interface Information**

The information in this section assumes familiarity with I2C programming.

#### How to program ASM3P2508A through I2C:

- Master (host) sends a start bit.
- · Master (host) sends the write address D4 (H).
- ASM3P2508A device will acknowledge.
- Master (host) sends the beginning byte location (N = 0, 1).
- ASM3P2508A device will acknowledge.
- Master (host) sends a byte count (X = 1,2)
- ASM3P2508A device will acknowledge.
- Master (host) starts sending byte N through byte (N+X - 1)
- ASM3P2508A device will acknowledge each byte one at a time.
- · Master (host) sends a Stop bit.

Controller (Host)	ASM3P2508A (slave/receiver)
Start Bit	
Slave Address D4(H)	A
	ACK
Beginning byte location (=N)	
	ACK
Byte count (=X)	
	ACK
Beginning byte (Byte N)	
	ACK
Next Byte (Byte N+1)	
	ACK
Last Byte (Byte N+X-1)	
	ACK
Stop Bit	

#### How to Read from ASM3P2508A through I2C:

- Master (host) will send start bit.
- · Master (host) sends the write address D4 (H).
- ASM3P2508A device will acknowledge.
- Master (host) sends the beginning byte location (N = 0, 1).
- ASM3P2508A device will acknowledge.
- · Master (host) will send a separate start bit.
- Master (host) sends the read address D5 (H).
- ASM3P2508A device will acknowledge.
- ASM3P2508A device will send the byte count (X = 1, 2).
- · Master (host) acknowledges.
- ASM3P2508A device sends byte N through byte (N+X - 1).
- Master (host) will need to acknowledge each byte.
- Master (host) will send a stop bit.

Controller (Host)	ASM3P2508A (slave/receiver)
Start Bit	
Slave Address D4(H)	
	ACK
Beginning Byte = N	
	ACK
Repeat start	
Slave address D5(H)	
	ACK
	Byte Count (= X)
ACK	
	Beginning byte N
ACK	
	Next Byte N+1
ACK	
	Last Byte (Byte N+X-1)
Not Acknowledge	
Stop Bit	



An example of a Byte Write via I2C to partially 'power down' the device:

ASM3P2508A can be partially 'powered down' using bit 1 of Byte 0. The organization of the register bits for Byte '0' is given with default values below:

Bit								
7	6	5	4	3	2	1	0	
Resv	Booy	Resv	Resv	Resv	Resv	PLL2	PLL1	
Resv	Resv	Resv	100	100	11001	Enable	Enable	
0	1	0	1	0	1	1	1	

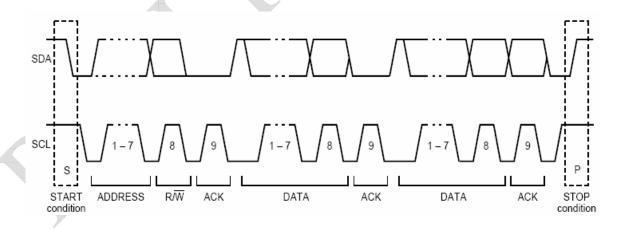
The function of partial power down of the device is of interest to us - that is bit 1 of Byte 0. In the default mode this bit is logic '1'. As such, the Byte 0 default value is

57 (H). To put ASM3P2508A in 'power down' mode, the bit 1 of Byte 0 is to be changed to logic '0'. Hence writing a 55 (H) via I2C into Byte 0 would put the device in partial 'power down' mode where the PLL block generating 72 MHz / 48 MHz would be powered down while I2C block, crystal oscillator, and the PLL block generating 120 MHz would still be active. The organization of the register bits is as below:

	Bit							
7	6	5	4	3	2	1	0	
Resv	Resv	Resv	Resv	Resv	Resv	PLL2	PLL1	
11031	100	1000	4	A		Enable	Enable	
0	1	0	1	0	1	0	1	

	Byte 0	Byte 1	FOUT1CLK (MHz)	FOUT2CLK(MHz)
Power up default	6F(H)	3F(H)	120	72
48_MHz Mode	6F(H)	BF(H)	120	48
Power down PLL with 72MHz	6D(H)	3F(H)	120	-
Power down PLL with 48MHz	6D(H)	BF(H)	120	-

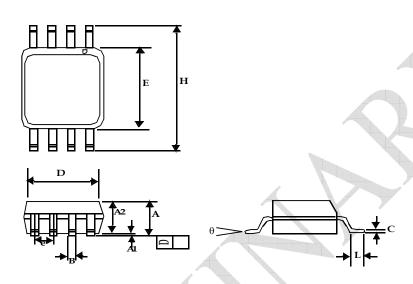
### Figure showing a complete data transfer:





# **Package Information**

# 8-Pin SOIC Package



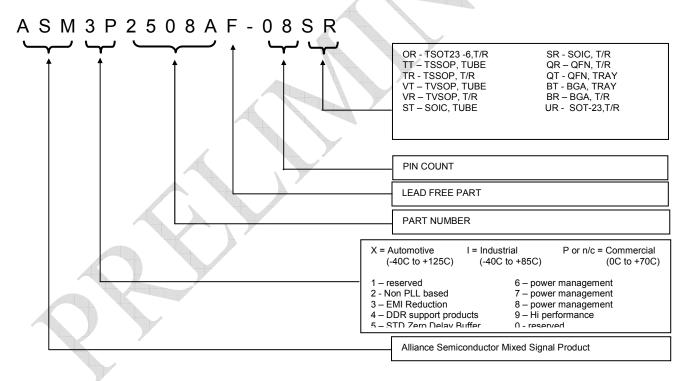
	Dimensions					
Symbol	Inc	hes	Millimeters			
	Min	Max	Min	Max		
A1	0.004	0.010	0.10	0.25		
Α	0.053	0.069	1.35	1.75		
A2	0.049	0.059	1.25	1.50		
В	0.012	0.020	0.31	0.51		
С	0.007	0.010	0.18	0.25		
D	0.193	BSC	4.90 BSC			
E	0.154	BSC	3.91	BSC		
е	0.050 BSC		1.27 BSC			
Н	0.236 BSC		6.00	BSC		
L	0.016	0.050	0.41	1.27		
θ	0°	8°	0°	8°		



### **Ordering Codes**

Part number	Marking	Package Configuration	Temperature
ASM3P2508A-08-ST	3P2508A	8-PIN SOIC, TUBE	Commercial
ASM3P2508A-08-SR	3P2508A	8-PIN SOIC, TAPE AND REEL	Commercial
ASM3I2508A-08-ST	3I2508A	8-PIN SOIC, TUBE	Industrial
ASM3I2508A-08-SR	3I2508A	8-PIN SOIC, TAPE AND REEL	Industrial
ASM3P2508AF-08-ST	3P2508AF	8-PIN SOIC, TUBE, Pb Free	Commercial
ASM3P2508AF-08-SR	3P2508AF	8-PIN SOIC, TAPE AND REEL, Pb Free	Commercial
ASM3I2508AF-08-ST	3I2508AF	8-PIN SOIC, TUBE, Pb Free	Industrial
ASM3I2508AF-08-SR	3I2508AF	8-PIN SOIC, TAPE AND REEL, Pb Free	Industrial

### **Device Ordering Information**



Licensed under US patent #5,488,627, #6,646,463 and #5,631,920.





Alliance Semiconductor Corporation 2575, Augustine Drive, Santa Clara, CA 95054 Tel# 408-855-4900 Fax: 408-855-4999 www.alsc.com Copyright © Alliance Semiconductor All Rights Reserved Preliminary Information Part Number: ASM3P2508A Document Version: v1.3

Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to Alliance Semiconductor, dated 11-11-2003

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